

PUSH-PULL H-F BEAM POWER AMPLIFIER

Unless otherwise specified, values are for both units

Electrical: Heaters, for Unipotential Cathodes. Arrangement Series Parallel Voltage 12.6 ± 10% 6.3 ± 10% ac or dc volts Current 0.8 1.6 amp Transconductance, for plate Current of 25 ma. 4000 µmhos Grid-Screen Mu-Factor 6.5 Direct Interelectrode Capacitances (Each Unit):* Grid No.1 to Plate 0.22 max µµf Input 14 µµf Output 8.5 µµf Mechanical: Mounting Position Vertical, base up or down; or Horizontal, plane of plates vertical Overall Length 3-13/16" ± 3/16" Maximum Diameter 2-3/8" Bulb 1-16 Caps (Two) Small Base Large Wafer Octal 8-Pin Micanol with Sleeve No. 7253 Basing Designation for BOTTOM VIFW 8BY Pin 1 - Heater Pin 2 - Grid No.1 of Unit No.2 Pin 3 - Cathode, Grid No.3, Internal Shield Pin 4 - Grid No.2 Pin 5 - Heater Center-Tap Plane of Electropors of Each Unit) Is PARALLEL TO PLANE THROUGH AND FLANE OF ELECTRODES of Each Unit) Fin 8 - Heater Pul 1 - Plate of Unit No.2 PLATE-MODULATED PUSH-PULL RF POWER AMP - Class C Telephony Carrier conditions per tube for use with a maximum average modulation factor of 0.25 Maximum Ratings, Absolute Values: DC PLATE VOLTAGE 560 max. volts DC GRID-No.1 (CONTROL-GRID) VOLTAGE 225 max. volts DC GRID-No.1 (CONTROL-GRID) VOLTAGE 175 max. volts	Unless otherwise	specifiea,	values	are jor	ooth uni	t S
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Grid-Screen Mu-Factor . 6.5 Direct Interelectrode Capacitances (Each Unit):* Grid No.1 to Plate . 0.22 max				•		,
Mechanical: Mounting Position Vertical, base up or down; or Horizontal, plane of plates vertical 4-3/8" ± 3/16" Seated Length 4-3/8" ± 3/16" Seated Length	<pre>Grid-Screen Mu-Factor Direct Interelectrode Grid No.1 to Plate.</pre>	Capacitano	5 ces (Eac 2 max		· · · · · *	ր դու
Mechanical: Mounting Position						
Mounting Position Vertical, base up or down; or Horizontal, plane of plates vertical 4-3/8" ± 3/16" Seated Length	,	0.0				, .
Horizontal, plane of plates vertical Overall Length				, ,		
PLATE-MODULATED PUSH-PULL RF POWER AMP. — Class C Telephony Carrier conditions per tube for use with a maximum average modulation factor of 0.25 Maximum Ratings, Absolute Values: DC PLATE VOLTAGE	Overall Length Seated Length Maximum Diameter Bulb Caps (Two) Base Large Wafer Basing Designation Pin 1 - Heater Pin 2 - Grid No.1 of Unit No.2 Pin 3 - Cathode, Grid No.3, Internal Shield Pin 4 - Grid No.2	Horizor Octal 8-Pi for BOTTOM Pu ₂ (4) (2) KEY	in Micar VIFW.	ane of p	lates ve 4-3/8" ± 13/16" ± 	rtical 3/16" 3/16" 2-3/8" T-16 Small o.T253 8BY , 3, l .1 of o.1
DC PLATE VOLTAGE	PLATE-MODULATED PUSH-	PULL RF POW	VER AMP.	— Class		
DC PLATE VOLTAGE	Maximum Ratings, Abso	lute Values	:		TUS®	
*, *, See next page. ←Indicates a change.	DC GRID-No.2 (SCREEN) DC GRID-No.1 (CONTROL- DC PLATE CURRENT DC GRID-No.1 CURRENT.			· · · · ·	560 max. 225 max. 175 max. 160 max. 11 max.	volts volts ma. ma.
	*, •, See next page.			← i no	dicates a	change.



PUSH-PULL H-F BEAM POWER AMPLIFIER

GRID-No.2 INPUT		30	max.	watts watts
Heater negative with respect to cathode Heater positive with respect to cathode			-	volts volts
Typical Operation:	•	100	IIIax.	VOLES
DC Plate Voltage	•	560 200		volts
DC Grid-No.1 Voltage ^A		\ 18000 { -50	: :	ohms volts
Peak RF Grid-No.1-to-Grid-No.1 Voltage		ኒ 7700 130		ohms
DC Plate Current		160		
DC Grid-No.2 Current				
DC Grid-No.1 Current (Approx.)				
Driving Power (Approx.)	•			watt
Power Output (Approx.)	٠	67		watts
Maximum Circuit Values:				
Grid-No.1-Circuit Resistance§		30000	max.	ohms
PUSH-PULL RE POWER AMPLIFIER & OSCILLATOR	- 1	Class C	Tele	graphy
Key-down conditions per tube without	# cd	ulation	#i	
Maximum Ratings, Absolute Values:	ni Ott	# tu v v o	<i>n</i> -	
maximum katings, Absolute rulues.		I.4S	•	
DC DIATE HOLTACE				1.
DC PLATE VOLTAGE	•			volts volts
DC GRID-No.1 (CONTROL GRID) VOLTAGE				volts
DC PLATE CURRENT				ma.
DC GRID-No.1 CURRENT			max.	
PLATE INPUT		100	max.	watts
GRID-No.2 INPUT		6	max.	watts
PLATE DISSIPATION	•	35	max.	watts
PEAK HEATER-CATHODE VOLTAGE:		100		1
Heater negative with respect to cathode Heater positive with respect to cathode				volts
	•	100	max.	VUILS
Typical Operation:				
OC Plate Voltage		600		volts
DC Grid-No.2 Voltage [®]	. 4	200		volts
		20000		ohms volts
DC Grid-No.1 Voltage t		7850		ohms
	• '	295		chms
Peak RF Grid-No.1-to-Grid-No.1 Voltage				volts
DC Plate Current		160		
DC Grid-No.2 Current		20		ma.
	•			
DC Grid-No.1 Current (Approx.)	·	7		ma.
DC Grid-No.1 Current (Approx.)		7		ma.





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Toner output (Approx.)	Driving Power (Approx.) Power Output (Approx.)			:	:	:	:	:	:	:	:	0.45 72	:	:	watt watts
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Maximum Circuit Values:

Grid-No.1-Circuit Resistance§. 30000 max. ohms

• Intermittent Mobile Service (IMS) is defined to include those applications, such as aircraft, where the transmitter design factors of minimum size, light weight, and exceedingly high power output for short intervals are the primary requirements, even though the average life expectancy of tubes used in such transmitters is reduced to about 100 hours.

Tube ratings for IMS service are established on the basis that the transmissions have maximum "on" periods of 15 seconds followed by "off" periods of at least 60 seconds, except that it is permissible to make equipment tests with maximum "on" periods of 5 minutes followed by off periods of at least 5 minutes provided the total "on" time of such periods does not exceed 10 hours during the life of any tube.

Although the use of tubes under IMS ratings involves great reduction in tube life, such use can be justified as economical practice in applications where high power is intermittently desired from small tubes.

- With no external shielding.
- Obtained preferably from a separate source modulated with the plate supply or from the modulated plate-supply through a series resistor of the value shown.
- Δ Obtained from grid-resistor of value shown or by partial self-bias methods.
- Modulation essentially negative may be used if the positive peak of the audio-frequency envelope does not exceed 115% of carrier conditions.
- Obtained preferably from a separate source, or from the plate-voltage supply with a voltage divider, or through a series resistor of the value shown. The grid-No.2 voltage must not exceed 600 volts under key-up conditions.
- Obtained from fixed-supply, by grid resistor of value shown, or cathode resistor of value shown, respectively.
- $\mathack{\S}$ Any additional bias required must be supplied by a cathode resistor or a fixed supply.

OUTLINE DIMENSIONS AND CURVES for the 3E22 are the same as those for the 815.